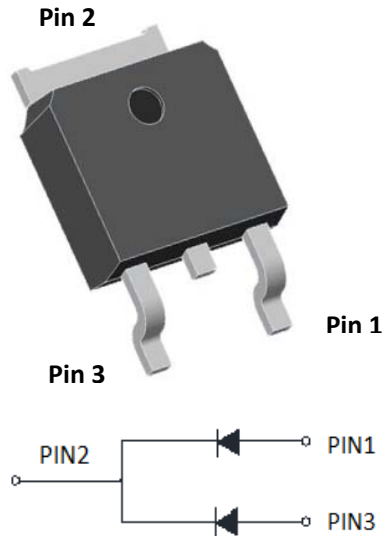


## Schottky Diodes



### Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-252  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR2045CD
Device marking code			MBR2045CD
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, T <sub>c</sub> =87°C	I <sub>O</sub>	A	20
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>a</sub> =25°C	IFSM	A	130
Current Squared Time @1ms≤t≤8.3ms T <sub>j</sub> =25°C,	I <sup>2</sup> t	A <sup>2</sup> s	70
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +150
Junction Temperature	T <sub>j</sub>	°C	-55 ~ +150

### ■Electrical Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR2045CD
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.63
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>RRM1</sub>	mA	V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =25°C	0.2
	I <sub>RRM2</sub>		V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =125°C	100

### ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR2045CD	
Thermal Resistance	Between junction and case	R <sub>θJ-C</sub>	°CW	5.0



# MBR2045CD

## Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR2045CD	Approximate 0.32	2500	2500	25000	Reel

## Characteristics (Typical)

FIG1:Io -Tc Curve

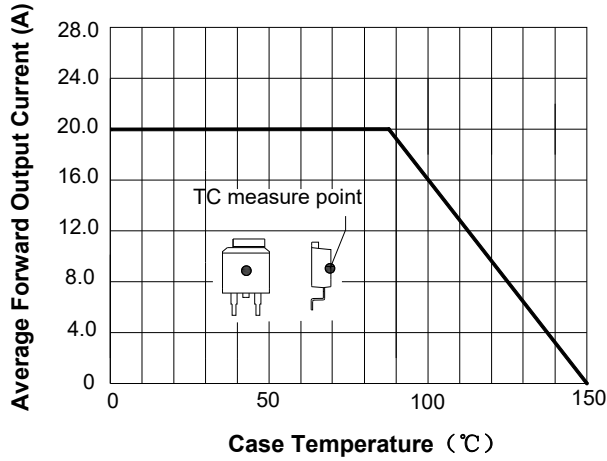


FIG2: Surge Forward Current Capability

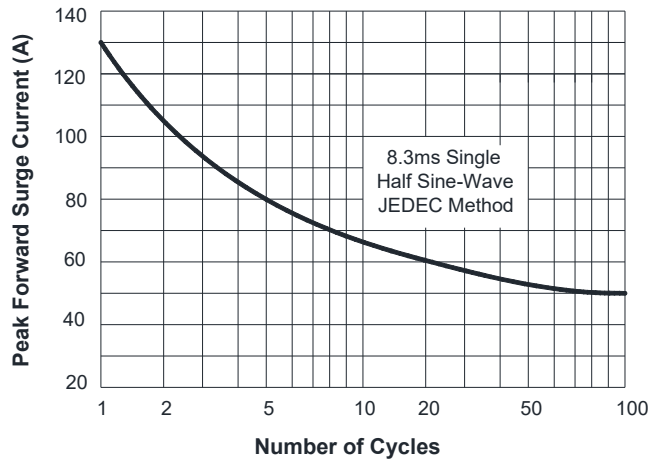


FIG3: Forward Voltage

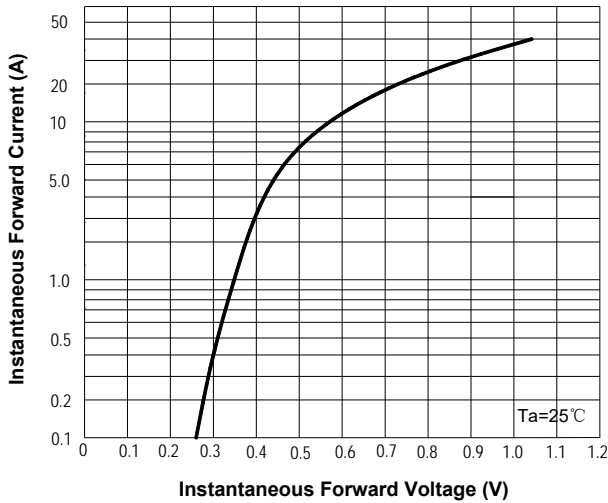
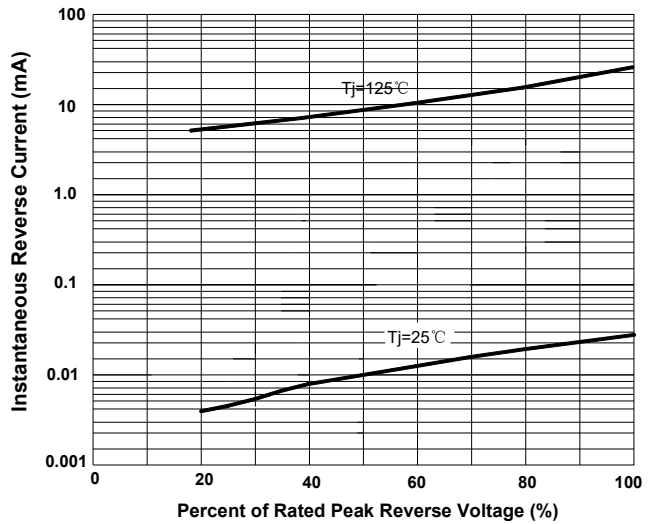


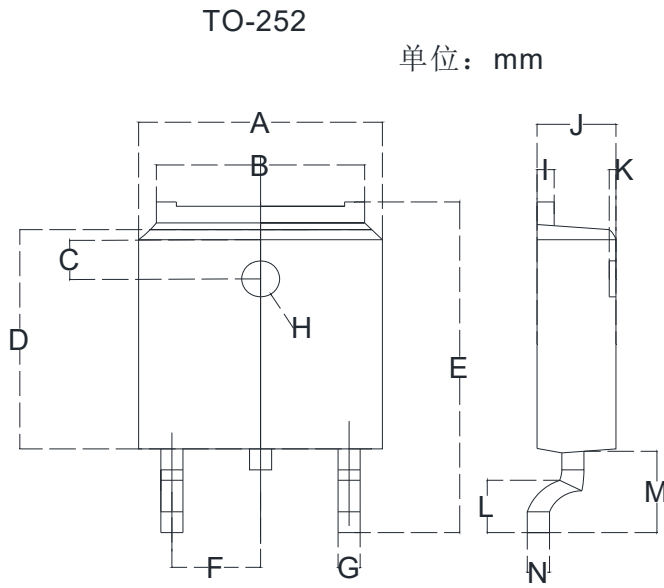
FIG4: Typical Reverse Characteristics





# MBR2045CD

## ■Outline Dimensions



TO-252		
Dim	Min	Max
A	6.500	6.700
B	5.100	5.460
C	1.400	1.800
D	6.000	6.200
E	10.000	10.400
F	2.166	2.366
G	0.660	0.860
H	Φ1.050	Φ1.350
I	0.460	0.580
J	2.200	2.400
K	0	0.300
L	0.890	2.290
M	2.730	3.080
N	0.430	0.580



## MBR2045CD

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